N-Channel 250-V (D-S) MOSFET

Key Features:

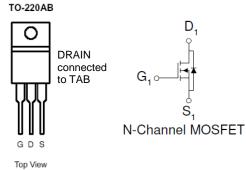
- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
250	300 @ V _{GS} = 10V	26 ^a	
	450 @ V _{GS} = 5.5V	20	





ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage		V_{DS}	250	V		
Gate-Source Voltage		V_{GS}	±20	V		
Continuous Drain Current a	T _C =25°C	I _D	26	Α		
sed Drain Current ^b		I _{DM}	100			
Continuous Source Current (Diode Conduction) ^a T _C =25°C		I _S	110	Α		
Power Dissipation	T _C =25°C	P_{D}	300	W		
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient °	$R_{\theta JA}$	62.5	°C/W
Maximum Junction-to-Case	$R_{\theta JC}$	1	C/VV

1

Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature
- c. Surface Mounted on 1" x 1" FR4 Board

Electrical Characteristics

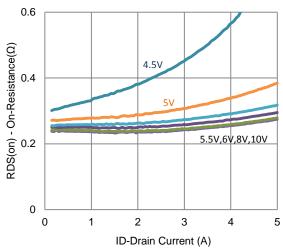
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 200 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
	I _{DSS}	$V_{DS} = 200 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
Drain-Source On-Resistance ^a	r	$V_{GS} = 10 \text{ V}, I_{D} = 5 \text{ A}$			300	mΩ	
	r _{DS(on)}	$V_{GS} = 5.5 \text{ V}, I_D = 4 \text{ A}$			450		
Forward Transconductance a	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		30		S	
Diode Forward Voltage ^a	V_{SD}	$I_{S} = 55 \text{ A}, V_{GS} = 0 \text{ V}$		0.9		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = 120 \text{ V}, V_{GS} = 5.5 \text{ V},$ $I_{D} = 5 \text{ A}$		15		nC	
Gate-Source Charge	Q_{gs}			7.7			
Gate-Drain Charge	Q_gd			6.2			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 120 \text{ V}, R_L = 24 \Omega,$ $I_D = 5 \text{ A},$ $V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		20		ns	
Rise Time	t _r			23			
Turn-Off Delay Time	$t_{d(off)}$			55			
Fall Time	t _f			46			
Input Capacitance	C _{iss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		1590		pF	
Output Capacitance	C _{oss}			140			
Reverse Transfer Capacitance	C_{rss}			95			

Notes

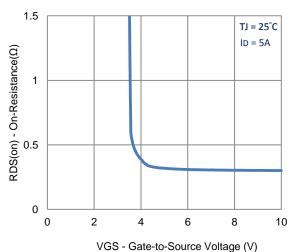
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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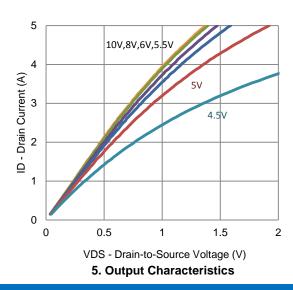
Typical Electrical Characteristics

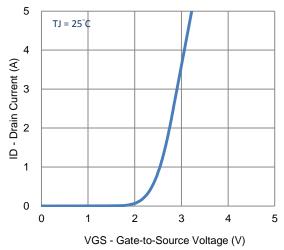


1. On-Resistance vs. Drain Current

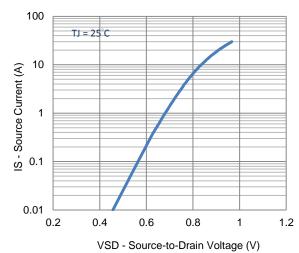


3. On-Resistance vs. Gate-to-Source Voltage

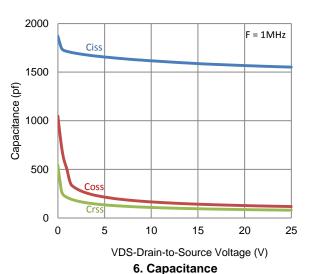




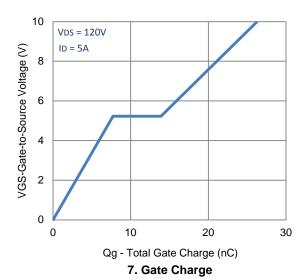
2. Transfer Characteristics

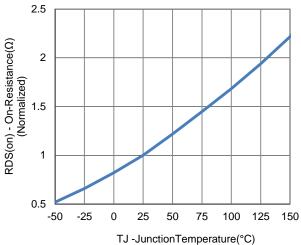


4. Drain-to-Source Forward Voltage

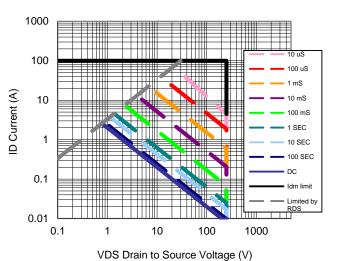


Typical Electrical Characteristics

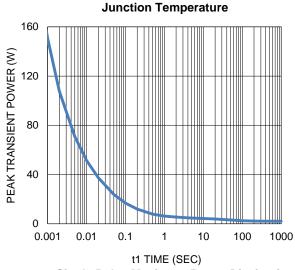




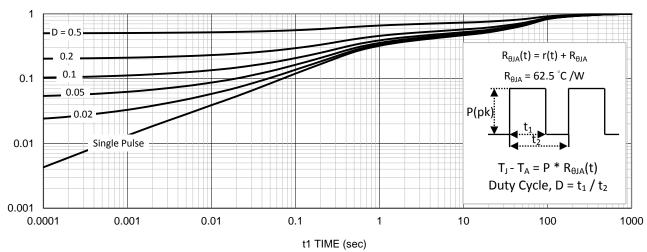
8. Normalized On-Resistance Vs



9. Safe Operating Area



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information

